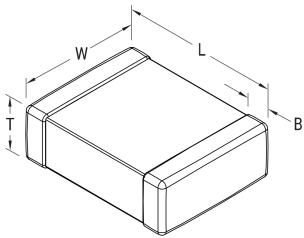


C1206C104K3GECAUTO

ESD SMD Auto COG, Ceramic, 0.1 uF, 10%, 25 VDC, COG, SMD, MLCC, Temperature Stable, Electro Static Discharge, Automotive Grade, 1206



Click here for the 3D model.

Dimensions	
Chip Size	1206
L	3.2mm +/-0.2mm
W	1.6mm +/-0.2mm
Т	1.6mm +/-0.20mm
В	0.5mm +/-0.25mm

Packaging Specifications	
Packaging	T&R, 180mm, Plastic Tape
Packaging Quantity	2000

SMD Auto COG Chip , MLCC, Temperature Stable, Electro Static
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perature Stable, Automotive Grade
-Q200
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Specifications	
Capacitance	0.1 uF
Measurement Condition	1 kHz 1.0Vrms
Capacitance Tolerance	10%
Voltage DC	25 VDC
ESD Level per AEC-Q200	25,000 V ESD Level
Dielectric Withstanding Voltage	62.5 VDC
Temperature Range	-55/+125°C
Temperature Coefficient	COG
Capacitance Change with Reference to +25°C and 0 VDC Applied (TCC)	30 ppm/C, 1kHz 1.0Vrms
Dissipation Factor	0.1% 1 kHz 1.0Vrms
Aging Rate	0% Loss/Decade Hour
Insulation Resistance	10 GOhms

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